

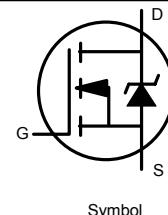
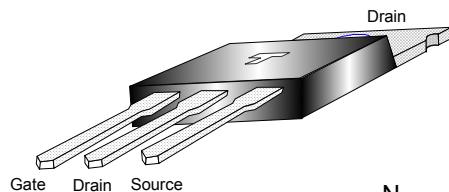


**Transys**  
**Electronics**  
**L I M I T E D**

**IRF630**

**Power MOSFET**

**$V_{DSS} = 200V$ ,  $R_{DS(on)} = 0.40 \text{ ohm}$ ,  $I_D = 9.0 \text{ A}$**



N  
Channel

ELECTRICAL CHARACTERISTICS at $T_j = 25^\circ\text{C}$ Maximum. Unless stated Otherwise					
Parameter	Symbol	Test Conditions		Value	Unit
		Min	Typ	Max	
Drain to Source Breakdown Voltage	$V_{BRDSS}$	$V_{GS} = 0 \text{ V}_{DC}$ , $I_D = 250 \mu\text{A}$	200	-	- Volt
Drain to Source Leakage Current	$I_{DSS}$	$V_{DS} = 200 \text{ V}_{DC}$ , $V_{GS} = 0 \text{ V}_{DC}$	-	-	25 $\mu\text{A}$
		$V_{DS} = 160 \text{ V}_{DC}$ , $V_{GS} = 0 \text{ V}_{DC}$ $T_j = 125^\circ\text{C}$	-	-	250 $\mu\text{A}$
Gate to Source Leakage Current	$I_{GSS}$	$V_{GS} = +20 \text{ V}_{DC}$	-	-	100 nA
		$V_{GS} = -20 \text{ V}_{DC}$	-	-	-100 nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250 \mu\text{A}$	2.0	-	4.0 Volt
Static Drain to Source On - Resistance	$R_{DS(on)}$	$V_{GS} = 10 \text{ V}_{DC}$ , $I_D = 3.1 \text{ A}$	-	-	0.40 $\Delta$
Gate Charge	$Q_G$	$I_D = 5.9 \text{ A}$	-	-	43 nC
Gate to Source Charge	$Q_{GS}$	$V_{DS} = 160 \text{ V}_{DC}$	-	-	7.0 nC
Gate to Drain Charge	$Q_{GD}$	$V_{GS} = 10 \text{ V}_{DC}$	-	-	23 nC
Input Capacitance	$C_{ISS}$		-	800	pF
Output Capacitance	$C_{OSS}$		-	240	pF
Transfer Capacitance	$C_{RSS}$		-	76	pF
Turn On Delay Time	$t_{d(on)}$		-	9.4	nS
Turn Off Delay Time	$t_{d(off)}$		-	39	nS
Rise Time	$t_r$		-	28	nS
Fall Time	$t_f$		-	20	nS
Continuous Source Current	$I_S$		-	-	9.0 A
Pulsed Source Current	$I_{SM}$		-	-	36 A
Forward Voltage (Diode)	$V_{SD}$	$V_{GS} = 0 \text{ V}_{DC}$ , $I_S = 9.0 \text{ A}$ , $T_p = 300 \mu\text{s}$	-	-	2.0 V

MAXIMUM RATINGS ( $T_j = 25^\circ\text{C}$ unless stated otherwise)				
Parameter	Symbol	Condition	Value	Unit
Gate to Source Voltage	$V_{GS}$		+/- 20V	Volt
Drain to Source Voltage	$V_{DSS}$		200	Volt
Continuous Drain Current	$I_D$		9.0	Amp
Pulsed Drain Current	$I_{DM}$	-	36	Amp
Total Power Dissipation	$P_D$	( $T_A = 25^\circ\text{C}$ )	74	W
Thermal Resistance (Junction to Ambient)	$R_{TH (J-A)}$		62	$^\circ\text{C/W}$

Maximum Operating Temperature Range ( $T_j$ )  $-55$  to  $+150^\circ\text{C}$   
Maximum Storage Temperature Range ( $T_{stg}$ )  $-55$  to  $+150^\circ\text{C}$

#### Mechanical Dimensions

DIMENSIONS				
	Millimetres		Inches	
Dim	Min	Max	Min	Max
a	10.29	10.54	0.405	0.415
b	2.62	2.87	0.103	0.113
c	6.10	6.47	0.240	0.255
d	3.54	3.78	0.139	0.149
e	14.84	15.24	0.584	0.600
f	13.47	14.09	0.530	0.555
g	1.15	1.400	0.045	0.055
h	1.15	1.400	0.045	0.055
j		2.54		0.100
k	3.550	4.06	0.140	0.160
m	4.20	4.69	0.165	0.185
n	1.22	1.32	0.048	0.052
p	2.64	2.92	0.104	0.115
q	0.48	0.55	0.018	0.022
r	0.69	0.93	0.027	0.037

